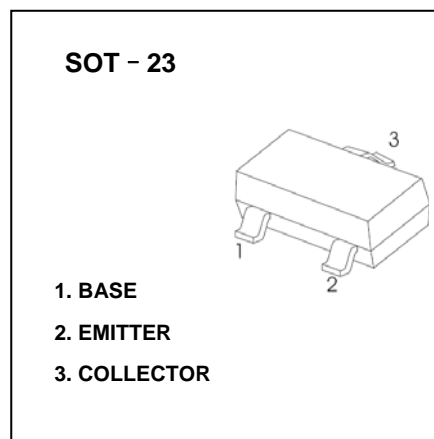


# SOT-23 Plastic-Encapsulate MOSFETS

## IRLML5203 P-Channel 30-V(D-S) MOSFET

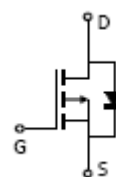
$V_{(BR)DSS}$	$R_{DS(on)MAX}$	$I_D$
-30V	85mΩ@-10 V	-3.0A
	145mΩ@-4.5V	



### General Description

The UMW IRLML5203TR uses advanced trench technology to provide excellent  $R_{DS(on)}$  with low gate charge. This device is suitable for use as a load switch or in PWM applications.

### Equivalent Circuit



### Maximum ratings ( $T_a=25^{\circ}C$ unless otherwise noted)

Parameter	Symbol	Value	Units
Drain-Source voltage	$V_{DS}$	-30	V
Gate-Source Voltage	$V_{GS}$	±20	V
Continuous Drain Current	$I_D$	-3.0	A
Drain Current-Pulsed	$I_{DM}$	-24	A
Power Dissipation	$P_D$	300	mW
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	417	$^{\circ}C/W$
Junction Temperature	$T_J$	150	$^{\circ}C$
Storage Temperature	$T_{STG}$	-55~ +150	$^{\circ}C$

# SOT-23 Plastic-Encapsulate MOSFETS

$T_a=25^{\circ}\text{C}$  unless otherwise specified

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
<b>Static characteristics</b>						
Drain-source breakdown voltage	$V_{(BR)DSS}$	$V_{GS} = 0V, I_D = -250\mu A$	-30			V
Zero gate voltage drain current	$I_{DSS}$	$V_{DS} = -24V, V_{GS} = 0V$			-1	$\mu A$
Gate -source leakage current	$I_{GSS}$	$V_{GS} = \pm 20V, V_{DS} = 0V$			$\pm 100$	nA
Drain-source on-resistance (note 1)	$R_{DS(on)}$	$V_{GS} = -10V, I_D = -4.1A$			85	m $\Omega$
		$V_{GS} = -4.5V, I_D = -3A$			145	m $\Omega$
Forward tranconductance (note 1)	$g_{FS}$	$V_{DS} = -5V, I_D = -4A$	5.5			S
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250\mu A$	-1		-3	V
Diode forward voltage (note 1)	$V_{SD}$	$I_S = -1A, V_{GS} = 0V$			-1	V
<b>Dynamic characteristics (note 2)</b>						
Input capacitance	$C_{iss}$	$V_{DS} = -15V, V_{GS} = 0V, f = 1MHz$		700		pF
Output capacitance	$C_{oss}$			120		pF
Reverse transfer capacitance	$C_{rss}$			75		pF
<b>Switching characteristics (note 2)</b>						
Turn-on delay time	$t_{d(on)}$	$V_{GS} = -10V, V_{DS} = -15V,$ $R_L = 3.6\Omega, R_{GEN} = 3\Omega$		8.6		ns
Turn-on rise time	$t_r$			5.0		ns
Turn-off delay time	$t_{d(off)}$			28.2		ns
Turn-off fall time	$t_f$			13.5		ns

**Notes:**

1. Pulse test: Pulse width  $\leq 300\mu s$ , Duty cycle  $\leq 2\%$ .
2. These parameter have no way to verify.

# SOT-23 Plastic-Encapsulate MOSFETS

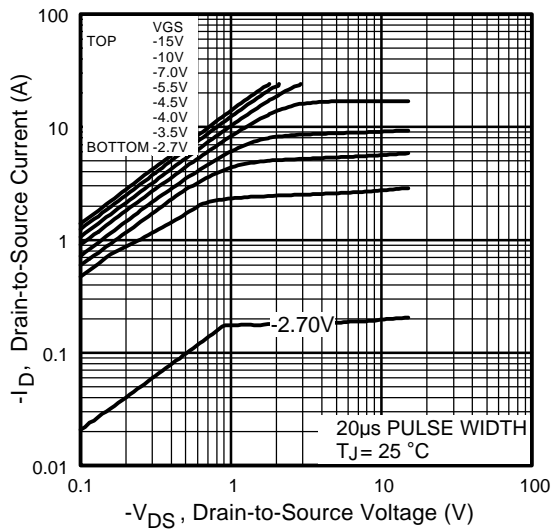


Fig 1. Typical Output Characteristics

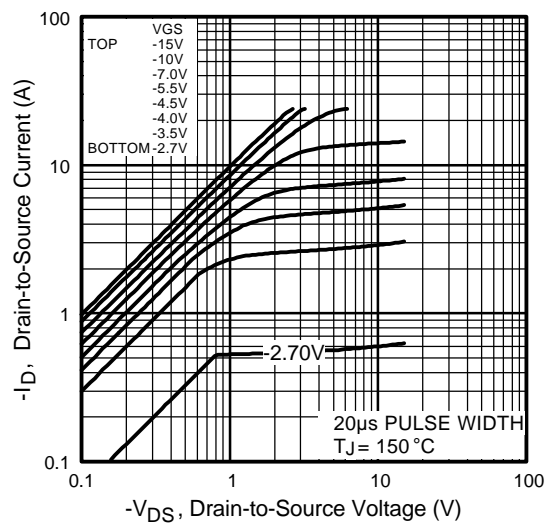


Fig 2. Typical Output Characteristics

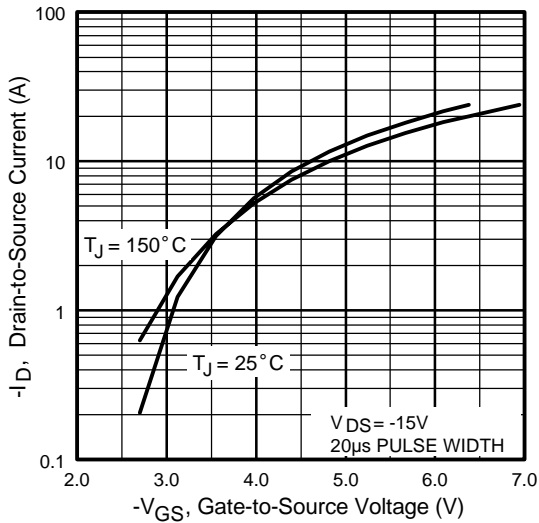


Fig 3. Typical Transfer Characteristics

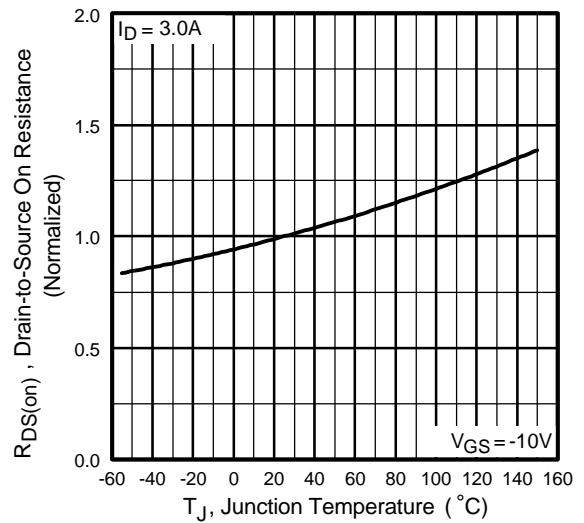


Fig 4. Normalized On-Resistance Vs. Temperature

# SOT-23 Plastic-Encapsulate MOSFETS

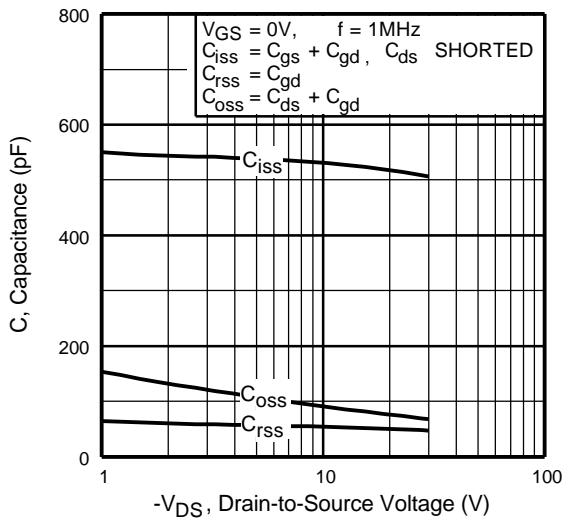


Fig 5. Typical Capacitance Vs. Drain-to-Source Voltage

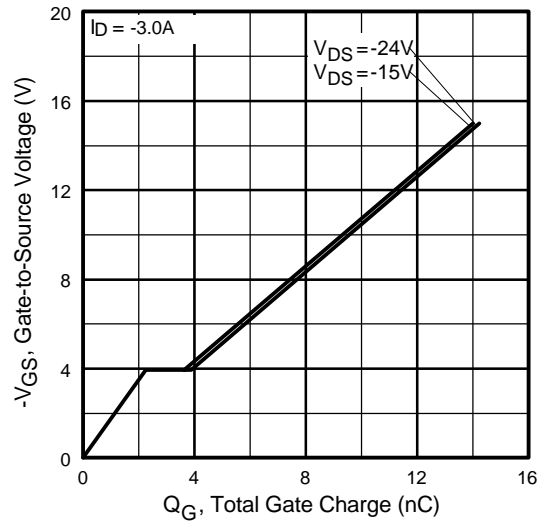


Fig 6. Typical Gate Charge Vs. Gate-to-Source Voltage

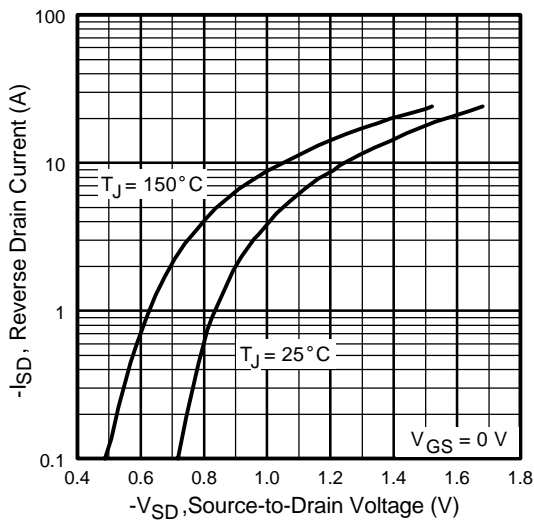


Fig 7. Typical Source-Drain Diode Forward Voltage

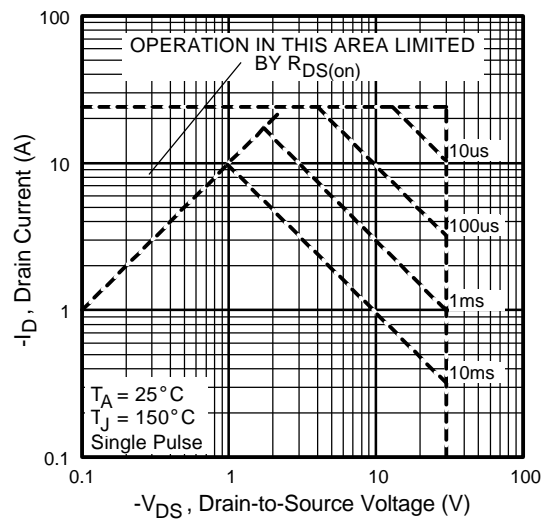
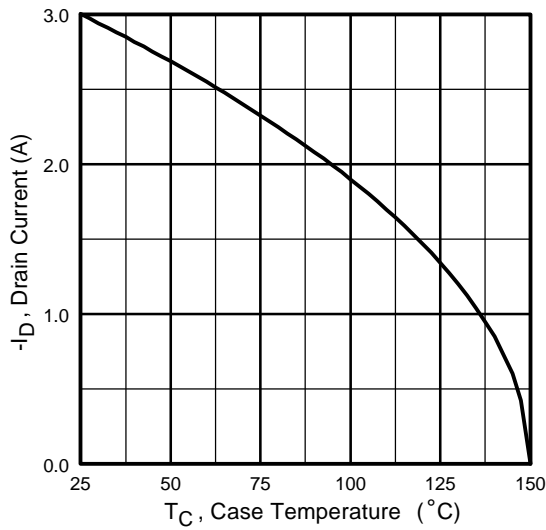
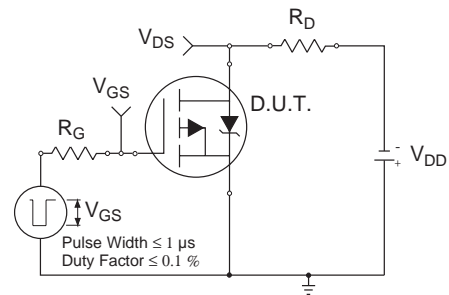


Fig 8. Maximum Safe Operating Area

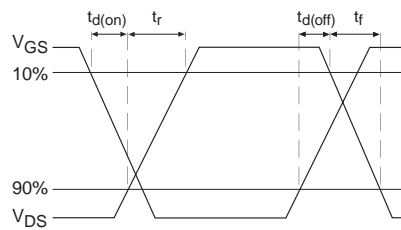
# SOT-23 Plastic-Encapsulate MOSFETS



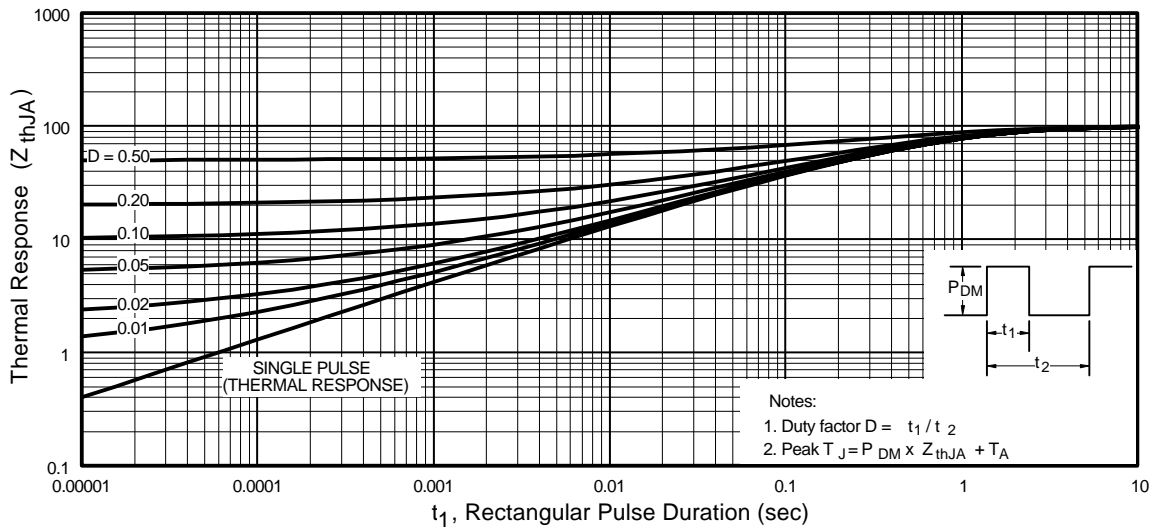
**Fig 9.** Maximum Drain Current Vs. Case Temperature



**Fig 10a.** Switching Time Test Circuit

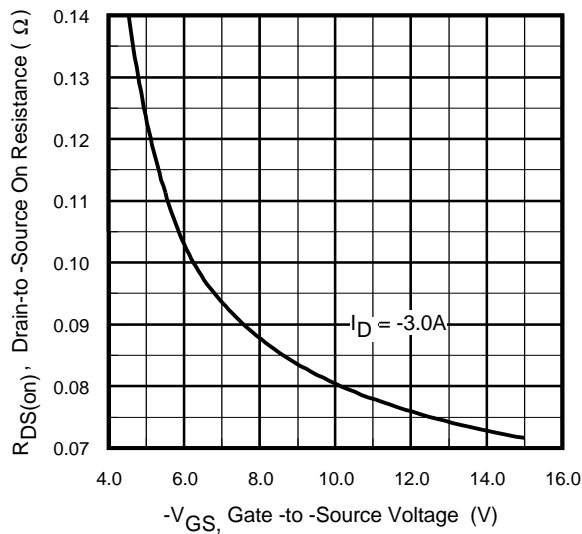


**Fig 10b.** Switching Time Waveforms

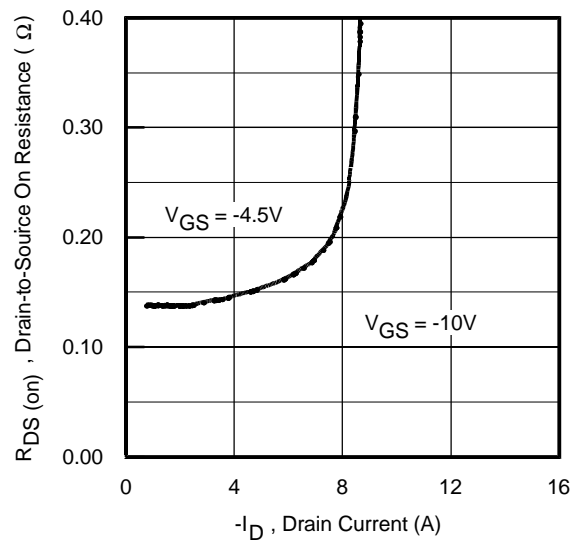


**Fig 11.** Maximum Effective Transient Thermal Impedance, Junction-to-Ambient

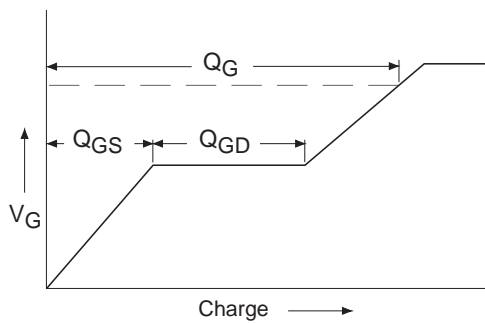
# SOT-23 Plastic-Encapsulate MOSFETS



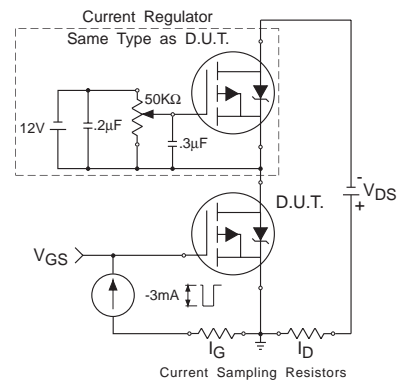
**Fig 11.** Typical On-Resistance Vs. Gate Voltage



**Fig 12.** Typical On-Resistance Vs. Drain Current

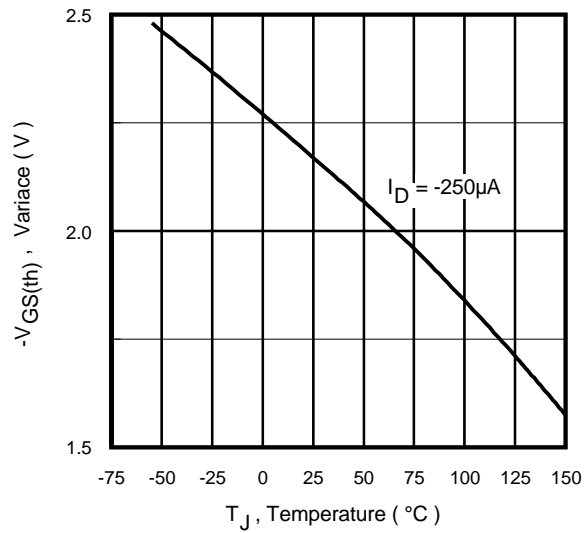


**Fig 13a.** Basic Gate Charge Waveform

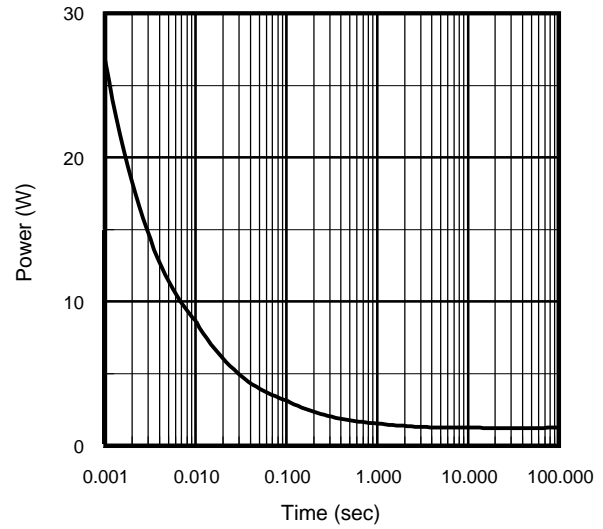


**Fig 13b.** Gate Charge Test Circuit

# SOT-23 Plastic-Encapsulate MOSFETS



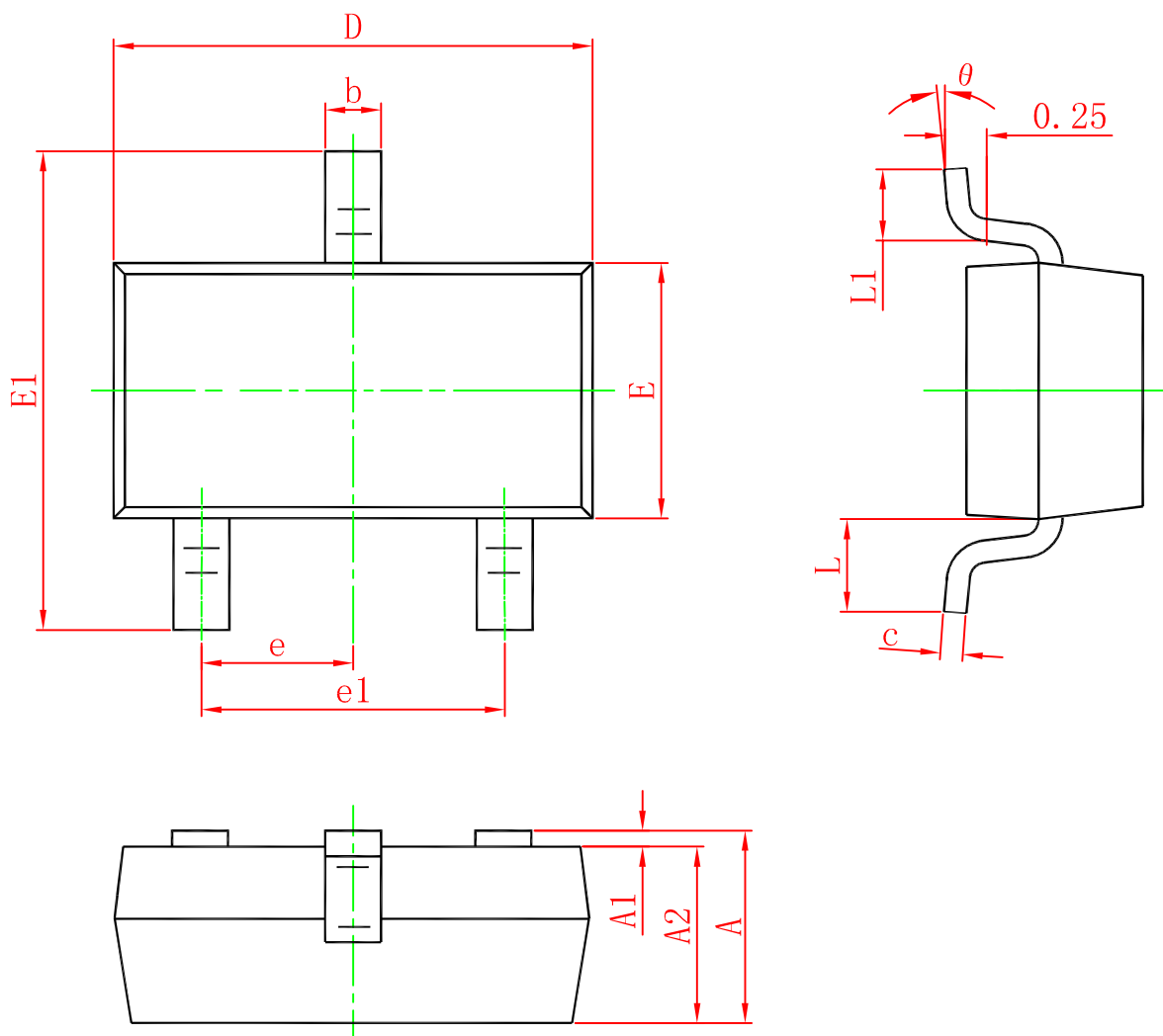
**Fig 14.** Threshold Voltage Vs. Temperature



**Fig 15.** Typical Power Vs. Time

# SOT-23 Plastic-Encapsulate MOSFETS

## SOT-23 PACKAGE OUTLINE DIMENSIONS

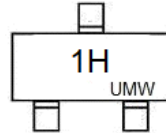


Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.900	1.150	0.035	0.045
A1	0.000	0.100	0.000	0.004
A2	0.900	1.050	0.035	0.041
b	0.300	0.500	0.012	0.020
c	0.080	0.150	0.003	0.006
D	2.800	3.000	0.110	0.118
E	1.200	1.400	0.047	0.055
E1	2.250	2.550	0.089	0.100
e	0.950 TYP.		0.037 TYP.	
e1	1.800	2.000	0.071	0.079
L	0.550 REF.		0.022 REF.	
L1	0.300	0.500	0.012	0.020
θ	0°	8°	0°	8°



# SOT-23 Plastic-Encapsulate MOSFETS

## Marking



## Ordering information

Order code	Package	Baseqty	Deliverymode
UMW IRLML5203TR	SOT-23	3000	Tape and reel